

**SHARP****NS-F135G5**

- Cell Material	135 Watt
- Number Of Cells	45 in series
- Cell Type	Tandem Structure. Thin Film Silicon
- Maximum power	144 Watt
- Minimum power	132 Watt
- Open Circuit Voltage (Voc)	61.3 Volt
- Short Circuit Current (Isc)	3.41 Ampere
- Maximum Power Voltage (Vpm)	47 Volt
- Maximum Power Current (Ipm)	2.88 Ampere
- Weight	26 Kg
- Dimension (HxWxD)	1402 x 1001 x 24 mm
- Module Efisiensi	9 %
- Max System Voltage	1.000 Volt
- Frame Material	Anodized Alumunium Alloy
- Front Cover Material	Low Iron Tempered Glasses
- Encapsulation Material	Black Color Resni Resin for Photovoltaic
- Bypass Diode	Installed in The Terminal Box
- BPPT (Badan Pengkajian dan Penerapan Teknologi) Certificate	

